



**ZXTD619MC**

**DUAL 50V NPN LOW SATURATION SWITCHING TRANSISTOR**

**Features**

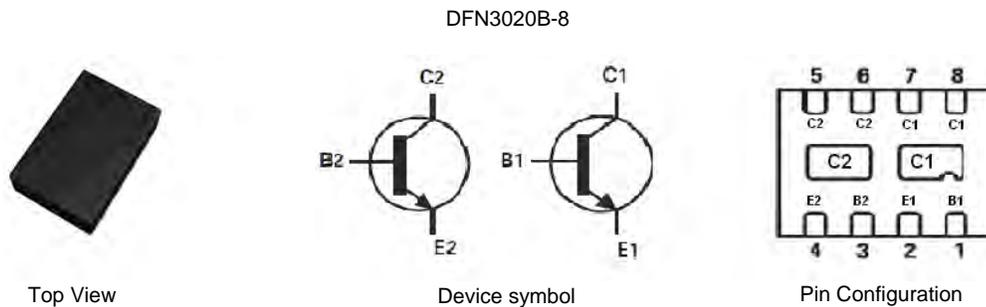
- $V_{CE0} = 50V$
- $R_{SAT} = 68m\Omega$
- $I_C = 4A$  Continuous Collector Current
- Low Equivalent On Resistance
- Low Saturation Voltage (100mV max @ 1A)
- $h_{FE}$  specified up to 6A
- **Lead, Halogen, and Antimony Free/RoHS Compliant (Note 1)**
- **"Green" Devices (Note 2)**

**Mechanical Data**

- Case: DFN3020B-8
- Case Material: Molded Plastic. "Green" Molding Compound.
- Terminals: Pre-Plated NiPdAu leadframe.
- UL Flammability Rating 94V-0
- Nominal package height: 0.8mm
- Moisture Sensitivity: Level 1 per J-STD-020
- Weight: 0.013 grams (approximate)

**Applications**

- DC – DC Converters (FET Drivers)
- Charging circuits
- Motor Control
- Power switches

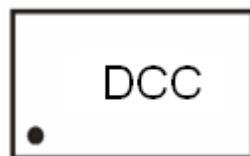


**Ordering Information**

Product	Status	Package	Marking	Reel size (inches)	Tape width (mm)	Quantity per reel
ZXTD619MCTA	Active	DFN3020B-8	DCC	7	8	3000

Notes: 1. No purposefully added lead. Halogen and Antimony Free.  
2. Diodes Inc's "Green" Policy can be found on our website at <http://www.diodes.com>

**Marking Information**



DCC = Product type Marking Code  
Dot Denotes Pin 1

## Maximum Ratings

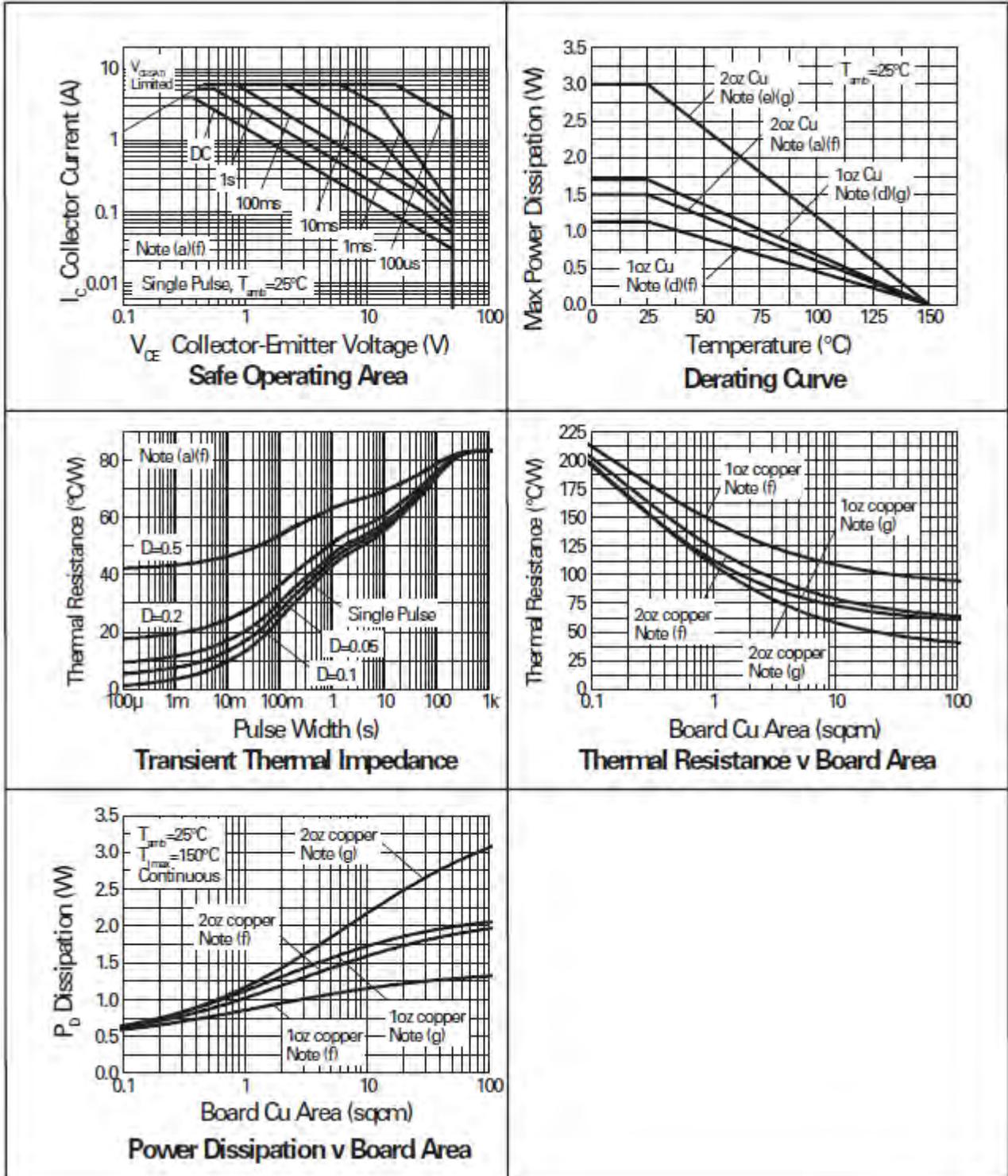
Parameter	Symbol	Limit	Unit
Collector-Base Voltage	$V_{CBO}$	100	V
Collector-Emitter Voltage	$V_{CEO}$	50	V
Emitter-Base Voltage	$V_{EBO}$	7.5	V
Peak Pulse Current	$I_{CM}$	6	A
Continuous Collector Current (Notes a and f)	$I_C$	4	A
Base Current	$I_B$	1	A

## Thermal Characteristics

Characteristic	Symbol	Value	Unit
Power Dissipation at $T_A = 25^\circ\text{C}$ (Notes a and f) Linear Derating Factor	$P_D$	1.5 12	W mW/ $^\circ\text{C}$
Power Dissipation at $T_A = 25^\circ\text{C}$ (Notes b and f) Linear Derating Factor	$P_D$	2.45 19.6	W mW/ $^\circ\text{C}$
Power Dissipation at $T_A = 25^\circ\text{C}$ (Notes c and f) Linear Derating Factor	$P_D$	1 8	W mW/ $^\circ\text{C}$
Power Dissipation at $T_A = 25^\circ\text{C}$ (Notes d and f) Linear Derating Factor	$P_D$	1.13 9	W mW/ $^\circ\text{C}$
Power Dissipation at $T_A = 25^\circ\text{C}$ (Notes d and g) Linear Derating Factor	$P_D$	1.7 13.6	W mW/ $^\circ\text{C}$
Power Dissipation at $T_A = 25^\circ\text{C}$ (Notes e and g) Linear Derating Factor	$P_D$	3 24	W mW/ $^\circ\text{C}$
Junction to Ambient (Notes a and f)	$R_{\theta JA}$	83.3	$^\circ\text{C}/\text{W}$
Junction to Ambient (Notes b and f)	$R_{\theta JA}$	51	$^\circ\text{C}/\text{W}$
Junction to Ambient (Notes c and f)	$R_{\theta JA}$	125	$^\circ\text{C}/\text{W}$
Junction to Ambient (Notes d and f)	$R_{\theta JA}$	111	$^\circ\text{C}/\text{W}$
Junction to Ambient (Notes d and g)	$R_{\theta JA}$	73.5	$^\circ\text{C}/\text{W}$
Junction to Ambient (Notes e and g)	$R_{\theta JA}$	41.7	$^\circ\text{C}/\text{W}$
Operating and Storage Temperature Range	$T_J, T_{STG}$	-55 to +150	$^\circ\text{C}$

- Notes:
- For a dual device surface mounted on 8 sq cm single sided 2 oz copper on FR4 PCB, in still air conditions **with all exposed pads attached**. The copper area is split down the centre line into two separate areas with one half connected to each half of the dual device.
  - Measured at  $t < 5$  secs for a dual device surface mounted on 8 sq cm single sided 2 oz copper on FR4 PCB, in still air conditions **with all exposed pads attached**. The copper area is split down the centre line into two separate areas with one half connected to each half of the dual device.
  - For a dual device surface mounted on 8 sq cm single sided 2 oz copper on FR4 PCB, in still air conditions **with minimal lead connections only**.
  - For a dual device surface mounted on 10 sq cm single sided 1 oz copper on FR4 PCB, in still air conditions **with all exposed pads attached**. The copper area is split down the centre line into two separate areas with one half connected to each half of the dual device.
  - For a dual device surface mounted on 85 sq cm single sided 2 oz copper on FR4 PCB, in still air conditions **with all exposed pads attached**. The copper area is split down the centre line into two separate areas with one half connected to each half of the dual device.
  - For a dual device with one active die.
  - For dual device with 2 active die running at equal power.

**Thermal Characteristics and Derating information**

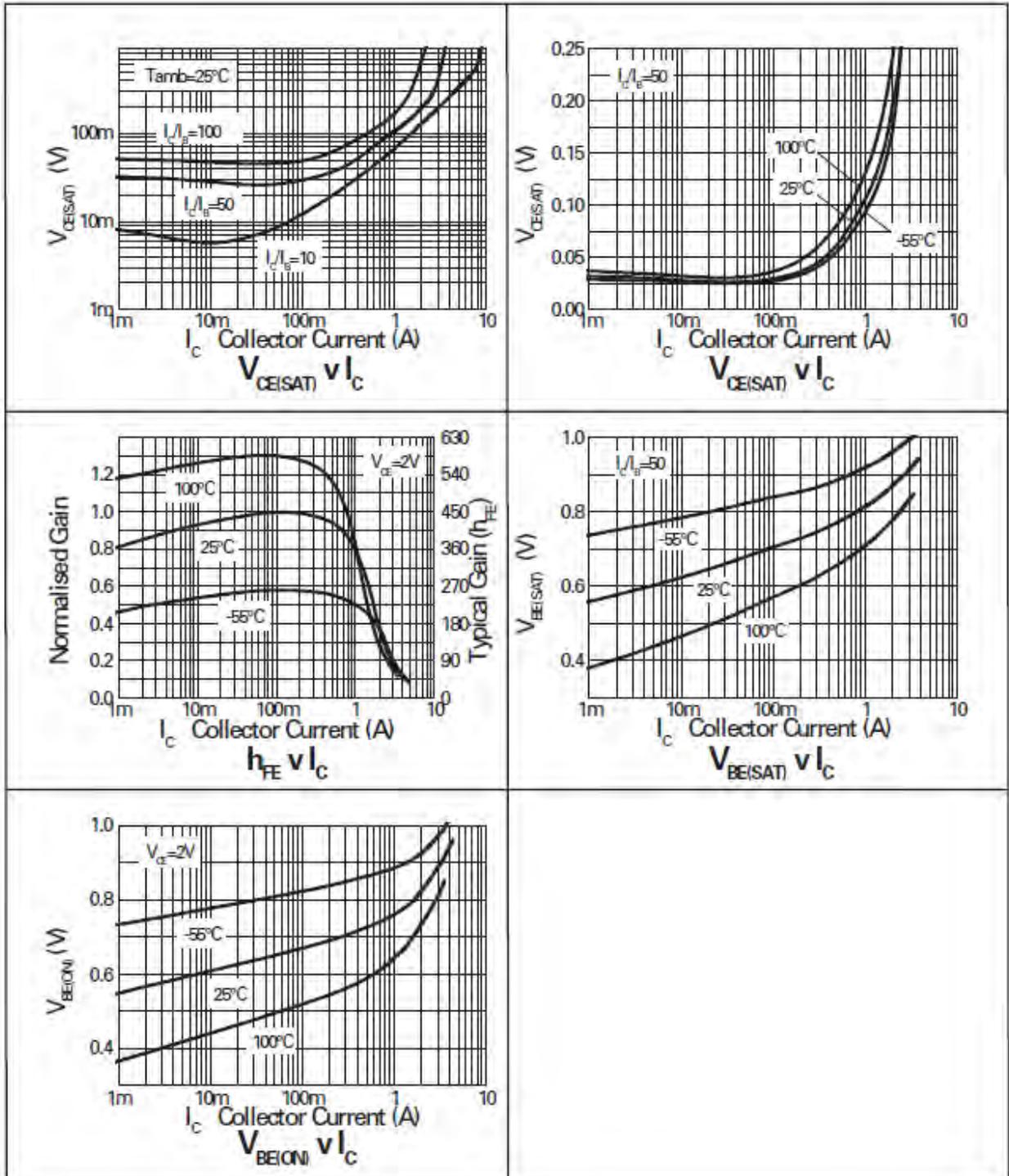


**Electrical Characteristics** @T<sub>A</sub> = 25°C unless otherwise specified

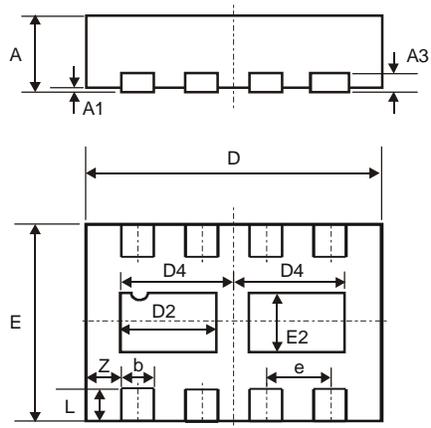
Characteristic	Symbol	Min	Typ	Max	Unit	Test Condition
Collector-Base Breakdown Voltage	V <sub>(BR)CBO</sub>	100	190	-	V	I <sub>C</sub> = 100μA
Collector-Emitter Breakdown Voltage (Note 3)	V <sub>(BR)CEO</sub>	50	65	-	V	I <sub>C</sub> = 10mA
Emitter-Base Breakdown Voltage	V <sub>(BR)EBO</sub>	7.5	8.2	-	V	I <sub>E</sub> = 100μA
Collector Cutoff Current	I <sub>CBO</sub>	-	-	25	nA	V <sub>CB</sub> = 80V
Emitter Cutoff Current	I <sub>EBO</sub>	-	-	25	nA	V <sub>EB</sub> = 6V
Collector Emitter Cutoff Current	I <sub>CES</sub>	-	-	25	nA	V <sub>CES</sub> = 40V
Static Forward Current Transfer Ratio (Note 3)	h <sub>FE</sub>	200	400	-	-	I <sub>C</sub> = 10mA, V <sub>CE</sub> = 2V
		300	450	-	-	I <sub>C</sub> = 200mA, V <sub>CE</sub> = 2V
		200	400	-	-	I <sub>C</sub> = 1A, V <sub>CE</sub> = 2V
		100	225	-	-	I <sub>C</sub> = 2A, V <sub>CE</sub> = 2V
		-	40	-	-	I <sub>C</sub> = 6A, V <sub>CE</sub> = 2V
Collector-Emitter Saturation Voltage (Note 3)	V <sub>CE(sat)</sub>	-	10	20	mV	I <sub>C</sub> = 0.1A, I <sub>B</sub> = 10mA
		-	70	100	mV	I <sub>C</sub> = 1A, I <sub>B</sub> = 5mA
		-	145	200	mV	I <sub>C</sub> = 1A, I <sub>B</sub> = 10mA
		-	115	220	mV	I <sub>C</sub> = 2A, I <sub>B</sub> = 50mA
		-	225	300	mV	I <sub>C</sub> = 3A, I <sub>B</sub> = 100mA
		-	270	320	mV	I <sub>C</sub> = 4A, I <sub>B</sub> = 200mA
Base-Emitter Turn-On Voltage (Note 3)	V <sub>BE(on)</sub>	-	0.94	1.00	V	I <sub>C</sub> = 4A, V <sub>CE</sub> = 2V
Base-Emitter Saturation Voltage (Note 3)	V <sub>BE(sat)</sub>	-	1.00	1.05	V	I <sub>C</sub> = 4A, I <sub>B</sub> = 200mA
Output Capacitance	C <sub>obo</sub>	-	12	20	pF	V <sub>CB</sub> = 10V, f = 1MHz
Transition Frequency	f <sub>T</sub>	100	165	-	MHz	V <sub>CE</sub> = 10V, I <sub>C</sub> = 50mA, f = 100MHz
Turn-on Time	t <sub>on</sub>	-	170	-	ns	V <sub>CC</sub> = 10V, I <sub>C</sub> = 1A
Turn-off Time	t <sub>off</sub>	-	750	-	ns	I <sub>B1</sub> = I <sub>B2</sub> = 10mA

Notes: 3. Measured under pulsed conditions. Pulse width = 300 μs. Duty cycle ≤ 2%

Typical Characteristics

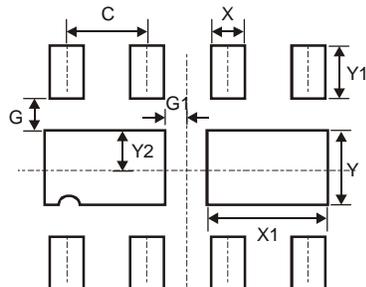


**Package Outline Dimensions**



DFN3020B-8			
Dim	Min	Max	Typ
A	0.77	0.83	0.80
A1	0	0.05	0.02
A3	-	-	0.15
b	0.25	0.35	0.30
D	2.95	3.075	3.00
D2	0.82	1.02	0.92
D4	1.01	1.21	1.11
e	-	-	0.65
E	1.95	2.075	2.00
E2	0.43	0.63	0.53
L	0.25	0.35	0.30
Z	-	-	0.375
All Dimensions in mm			

**Suggested Pad Layout**



Dimensions	Value (in mm)
C	0.650
G	0.285
G1	0.090
X	0.400
X1	1.120
Y	0.730
Y1	0.500
Y2	0.365

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